# NSN 5961-01-049-8368

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#### **Inclosure Material:**

Metal

**Overall Length:** 

0.210 inches

## **Terminal Length:**

0.500 inches

## **Overall Diameter:**

Between 0.209 inches and 0.230 inches

## Internal Configuration:

Field effect

#### **Mounting Method:**

Terminal

#### **Terminal Circle Diameter:**

0.100 inches

## Features Provided:

#### Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 60.0 breakdown voltage, gate-to-source,

with all other terminals short-circuited to source and 60.0 reverse gate to source voltage

## **Current Rating Per Characteristic:**

20.00 milliamperes drain current and 10.00 milliamperes gate current

## **Power Rating Per Characteristic:**

200.0 milliwatts total device dissipation

## **Test Data Document:**

77327-40704 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

3 uninsulated wire lead

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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